





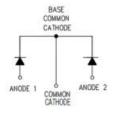
20CJQ060 SCHOTTKY RECTIFIER



Features

- 150 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- · Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units	
Peak Repetitive Reverse Voltage	V_{RRM}	-			
Working Peak Reverse Voltage	V_{RWM}		60	V	
DC Blocking Voltage	V_R				
Average Destified Ferward Current	1	50% duty cycle @Tc=127°C,	1(Per Leg)	۸	
Average Rectified Forward Current	IF (AV)	rectangular wave form	2(Per Device)	Α	
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _C = 25 °C	26	Α	

Electrical Characteristics:

Characteristics	Symbol	Symbol Condition		Max.	Units
Forward Voltage Drop	V _{F1}	@ 1A, Pulse, T _J = 25 °C	0.55	0.70	V
(Per Leg)*	V _{F2}	@ 1A, Pulse, T _J = 125 °C	0.48	0.65	V
Reverse Current (Per Leg)*	I _{R1}	$@V_R = rated V_R$ $T_J = 25 °C$	0.02	0.1	mA
	I _{R2}	$@V_R = rated V_R$ $T_J = 125 °C$	5	10.0	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	45	60	pF

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

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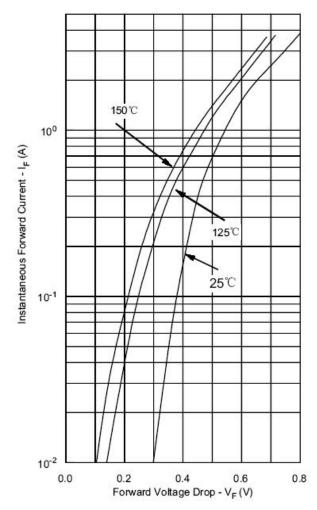


Thermal-Mechanical Specifications:

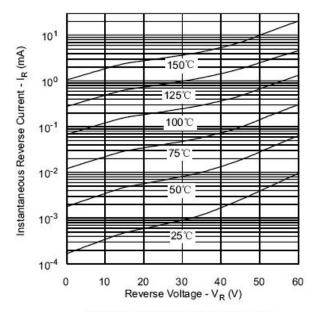
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	R ₀ JL	DC operation	25	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	65	°C/W
Approximate Weight	wt	-	0.13	g
Case Style	SOT-223			

Ratings and Characteristics Curves

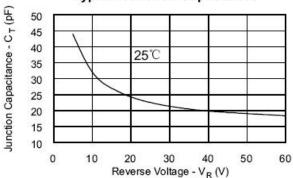
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



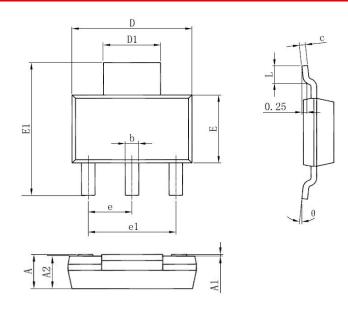
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Mechanical Dimensions SOT-223



OVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	1.520	1.800	0.060	0.071	
A1	0.000	0.100	0.000	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.820	0.026	0.032	
С	0.250	0.350	0.010	0.014	
D	6.200	6.400	0.244	0.252	
D1	2.900	3.100	0.114	0.122	
E	3.300	3.700	0.130	0.146	
E1	6.830	7.070	0.269	0.278	
е	2.300(BSC)		0.091(BSC)		
e1	4.500	4.700	0.177	0.185	
L	0.900	1.150	0.035	0.045	
θ	0°	10°	0°	10°	

Ordering Information

Device	Package	Shipping
20CJQ060	SOT-223 (Pb-Free)	3000pcs / reel
20CJQ060TR	SOT-223 (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 20CJQ060
 = Part Name

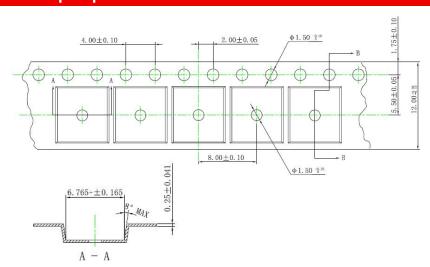
 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Carrier Tape Specification SOT-223





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